Novel device behaviors at low dimensional heterojunctions in 2-D materials

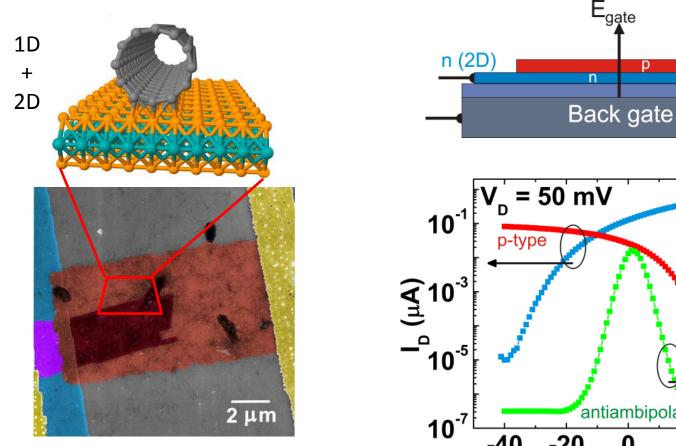
Lincoln J. Lauhon

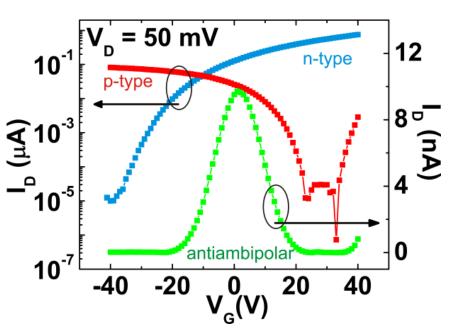
Department of Materials Science & Engineering



2-D Geometry Produces New Functions

Hersam, Marks, Lauhon et al, PNAS USA, 110, 18076 (2013).





p(0/1/2D)

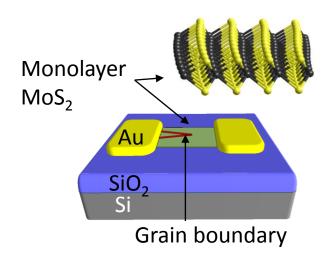
Dielectric

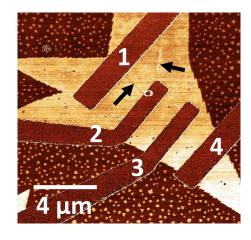
Concept generalized in Hersam, Marks, Lauhon et al, Nano Letters 15, 416 (2015).

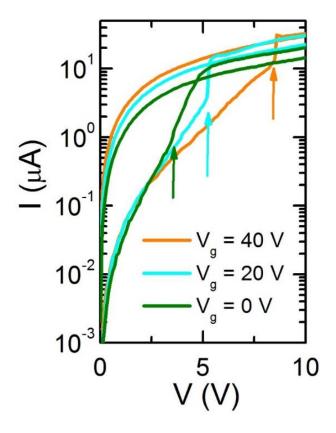
Electrical **Optical** Spin Mechanical Interfaces **Defects**

Grain boundaries lead to memristive behavior

Hersam, Marks, Lauhon, Nature Nanotechnology 10, 403 (2015)



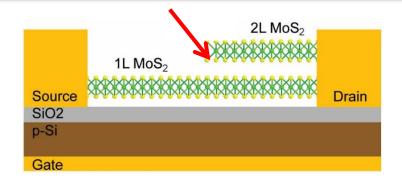




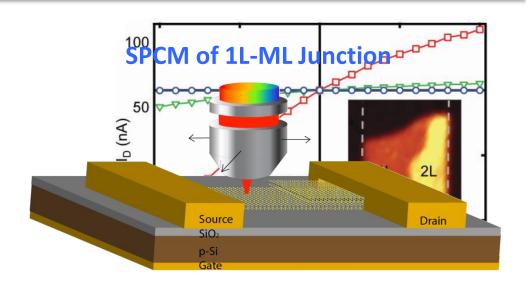
- Hysteretic I-V curve with low and high resistance states → memristor.
- Switching ratio (ON/OFF) ~ 10³
- Observed in devices with grain boundaries and sulfur vacancies.

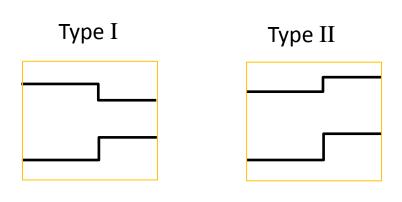
Unique opportunity for neuromorphic computing

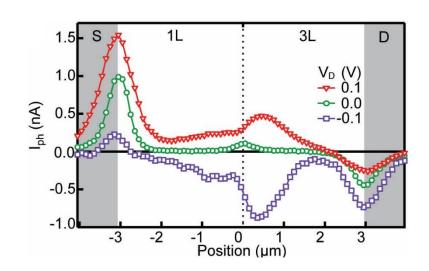
A new type of heterojunction in MoS₂



Thickness-dependent bandstructure results in fundamentally new type of semiconductor junction.



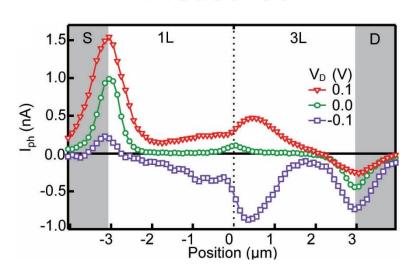




Howell, Jariwala, et al., Nano Lett., 15, 2278 (2015)

SPCM modeling extracts band profiles

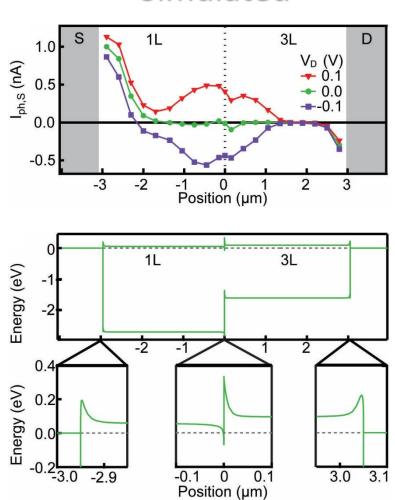
Measured



FE modeling based on material parameters determined from uniform thickness devices.

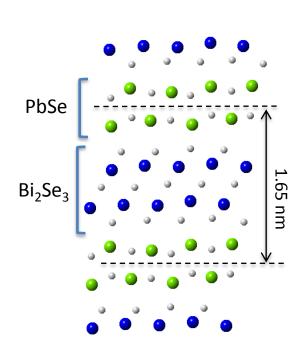
Simulations reproduce bias dependence assuming a type-2 band offset.

Simulated

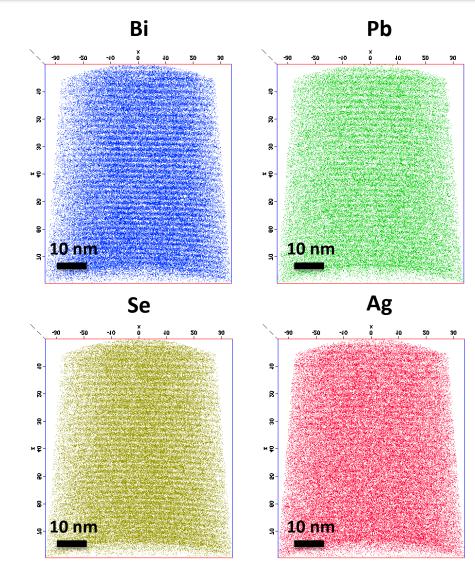


Electrical **Optical** Spin Mechanical Interfaces **Defects**

Atom Probe Tomography of a 2D Material: Ag doped (PbSe)₅(Bi₂Se₃)_{3m}



- Ag doping changes m=1 phase from metallic to superconducting.
- Ag is expected to dope only the PbSe layer. Can dopant location be resolved by APT?

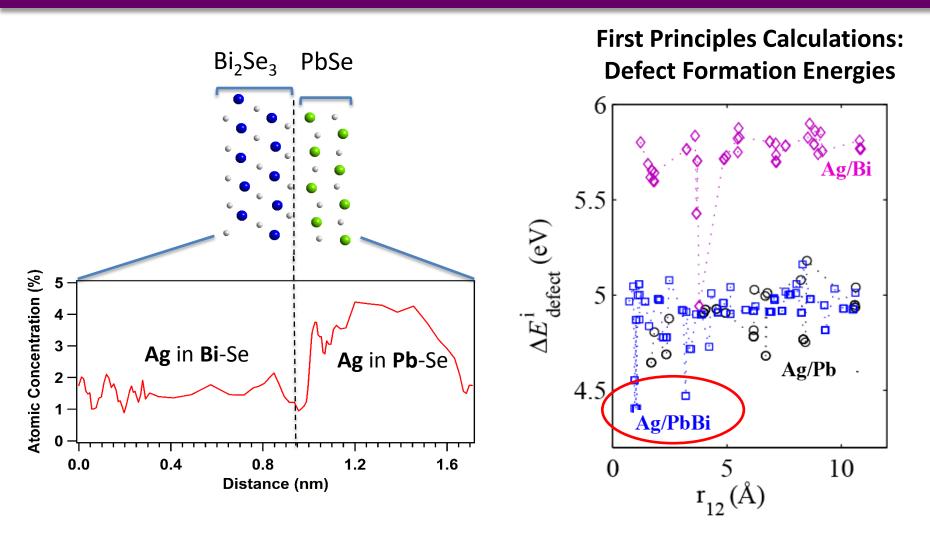


Ren, Lauhon et al, unpublished.

NU: Mercouri Kanatzidis

NIST: Singh, Tavazza

Atom probe shows Ag dopes both Pb and Bi layers

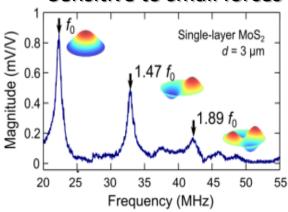


Significance: Validation of ability to predict and measure dopant locations in 2-D materials.

Electrical Spin Mechanical Optical Interfaces **Defects**

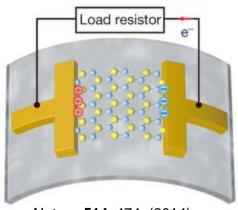
Mechanical Properties of MoS₂ Membranes

Sensitive to small forces



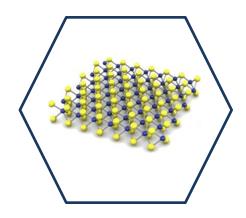
Adv. Mater. 25, 6719 (2013)

Piezoelectric Monolayer

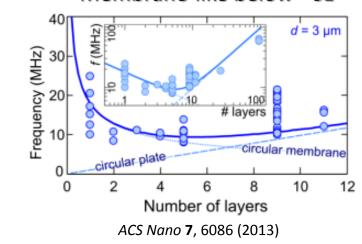


Nature **514**, 474 (2014)

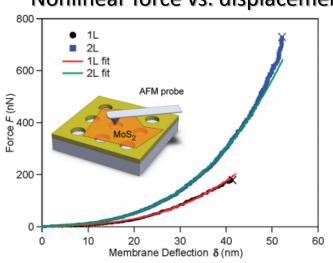
$f = \frac{2.4048}{\pi d} \sqrt{\frac{T}{\rho t}}$



Membrane-like below ~6L



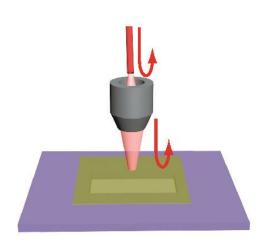
Nonlinear force vs. displacement



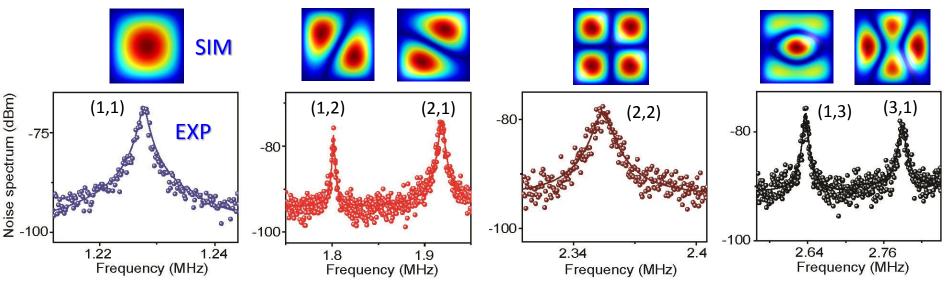
ACS Nano 5, 9703 (2011)

Annalen der Physik **527**, 27 (2015)

Modes identified from thermal fluctuations

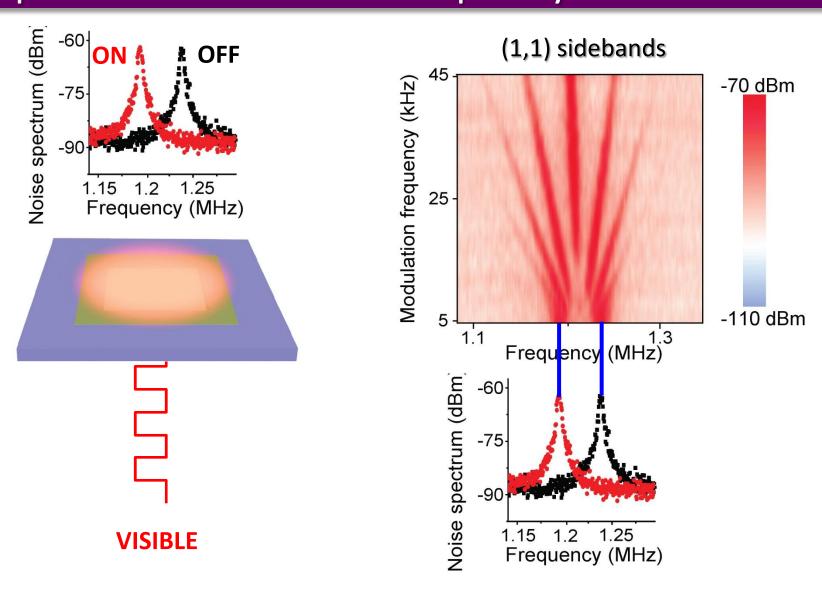


- Thermally excited vibrational modes are observed and identified.
- Nominally degenerate modes are split.
 - Could indicate mode-coupling.



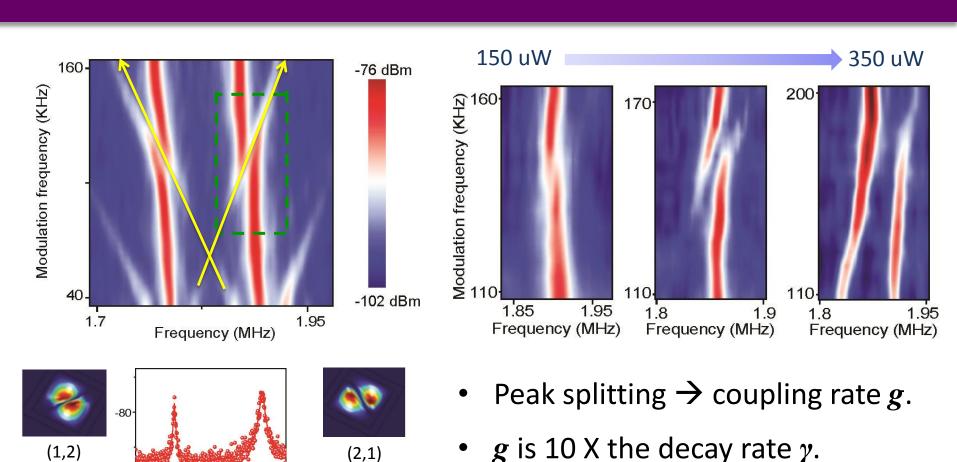
Liu and Lauhon, Nano Lett ASAP.

Distribution of thermal energy in mechanical modes depends on modulation frequency



Liu and Lauhon, Nano Lett ASAP.

Normal-mode splitting is observed



Strong coupling enables coherent energy exchange.

Liu and Lauhon, Nano Lett ASAP.

1.8

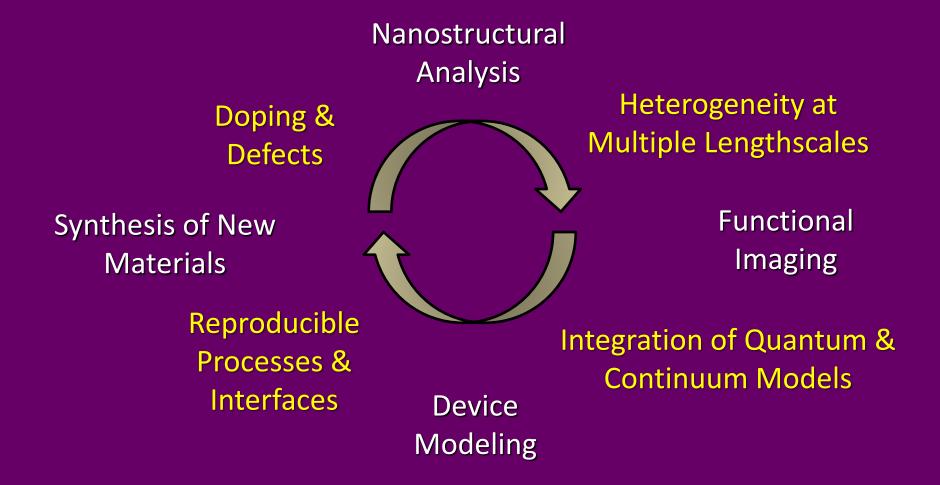
1.9

Frequency (MHz)

Electrical Spin Mechanical Optical Interfaces **Defects**

Electrical Spin Mechanical **Optical Defects** Interfaces

Challenges in 2-D Materials & Devices



Integrated approach to 2D MSE

Lauhon Research Group

Group:

Sarah Howell

(G-4)

Nari Jeon (G-4)

Spencer Park (UG)

Ryan Paull (G-1)

Xiaochen Ren (G-3)

Zhiyuan Sun (G-2)

KunHo Yoon (G-5)

Deep Jariwala (Hersam, Marks)

Cited Alumni:

Chung-Chiang Wu (PD)

Vinod Sangwan (PD)

In Soo Kim (PhD)

Collaborators:

Mark Hersam Northwestern

Tobin Marks Northwestern

Teri Odom Northwestern

M. Kanatzidis Northwestern

Gregor Koblmuller TU Munich

Yossi Rosenwaks Tel Aviv University

Arunima Singh NIST

Francesca Tavazza NIST

NUCAPT, **NU**ANCE





